Research Article

Benzene Oxidation on Boron-Doped Diamond Electrode: Electrochemical-Impedance Study of Adsorption Effects

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Benzene oxidation at a boron-doped diamond anode in 0.5 M K2SO4 aqueous solution is studied by cyclic voltammetry and electrochemical impedance spectroscopy. It is shown by measurements of differential capacitance and anodic current that in the ideal-polarizability potential region benzene either is not adsorbed at the diamond electrode or the benzene adsorption does not affect its capacitance. At more positive potentials, the adsorption of some intermediate of the benzene oxidation occurs at the electrode. The intermediate partially blocks the electrode surface and lowers the anodic current. The very fact of the electrode surface blocking is reflected in the complex-plane presentation of the impedance-potential plots.

1. Introduction

Boron-doped diamond (BDD) proved being a corrosion-stable electrode material, particularly suitable for deep anodic oxidation [1]. Indeed, the diamond electrode makes it possible reaching high anodic potentials at which hydroxyl radicals (OH•) are formed at the anode surface (the oxygen evolution overpotential for diamond is sufficiently large, so this electrochemical reaction occurs with high current efficiency). The radicals oxidize organic and inorganic solutes (carboxylic acids, alcohols, phenols, aromatics) in the course of homogeneous chemical reaction. For this process, a kinetic model was suggested [2], according to which one of the two oxidation mechanisms is realized. In the potential region, where water is electrochemically stable, direct electron transfer occurs, whereas at high anodic potentials, indirect oxidation involving the above-mentioned hydroxyl radicals as mediator takes place (with concurrent oxygen evolution). The anodic oxidation at boron-doped diamond is an effective method of the nature and waste water purification from organic and inorganic pollutants [3, 4].

Benzene and its derivatives are typical water pollutants. The benzene oxidation at boron-doped diamond in 0.5 M H2SO4 solution was studied in [5]. It was shown by using high-performance liquid chromatography that a mixture of the benzene oxidation intermediates (hydroquinone, resorcinol, p-benzoquinone, catechol, and phenol) was formed in solution at the anode potential of 2.5 V (versus Ag/AgCl-electrode). The benzene complete incineration yielding CO2 occurs at potentials more positive than 2.5 V. In our preceding paper [6], the benzene oxidation at boron-doped diamond anode was studied in 1 M HCl solution by electrochemical impedance spectroscopy, with special emphasis on the revealing of the role of adsorption in the process.

In this work, the benzene oxidation at boron-doped diamond anode was studied by electrochemical impedance spectroscopy with the purpose of having deeper insight in the oxidation process, in particular, in some delicate effects caused by the adsorption of benzene-oxidation intermediates at the electrode.

2. Experimental

2.1. Growth of Boron-Doped Diamond Films. Boron-doped diamond films were grown using hot-filament technique, by the depositing of diamond onto conducting silicon wafers from activated reaction gas phase. The gas phase activation was accomplished using a row of tungsten filaments arranged horizontally over the substrate surface at a distance of 5–10 mm. The filaments were heated up to ~2000°C. The
activator temperature was measured by monochromatic optical pyrometer through quartz window in the upper part of the reactor cap. The purpose of the activation is the formation, in the reaction gas, of large concentration of atomic hydrogen that ensures the selectivity of carbon deposition in the form of diamond.

A mixture of pure methane (ca. 1.2 vol%) with hydrogen (ultra-high purity grade, mark A, the Nauka Company production) was subjected to the activation. The gas mixture composition was controlled by automated gas flow regulators; the full pressure in the reaction gas mixture was 30–36 Torr.

The substrates were KDB-10 silicon plates sized 12 by 12 by 1 mm; the silicon resistivity was 10 Ohm cm. The substrates were arranged on water-cooled substrate holder, in particular, a copper table provided with heater that maintained a preset temperature 850–890°C. The substrate temperature was measured at the substrates’ rear side by another optical pyrometer through a special channel in the sample holder.

To impart sufficiently large conductivity to the diamond films, they were doped, during their deposition, with boron. To this purpose, the reaction gas mixture was added by acetone-methanol-trimethylborate solution vapors. The B/C concentration ratio in the reaction mixture was estimated as 2500–3500 ppm.

To shorten the crystallization incubation time and set up high diamond crystallization-center density, the substrate surface was polished by superdispersed diamond polishing paste. The film average thickness was determined by sample weighing prior to and after the film growth; it came to ~18 μm.

The as-grown films were subjected to heating in air at 520–530°C for 20 min, to free the diamond surface from traces of nondiamond carbon. The nondiamond carbon has been deposited from the reaction gas phase after its activation has been ceased, that is, at the poorly controlled final deposition stage, during the samples cooling in the reactor.

2.2. Electrochemical Measurements. Electrochemical cell-comprised diamond working electrode and platinum auxiliary electrode; the interelectrode distance was 5–7 mm. The anodic and cathodic compartments were not separated. The substrate with diamond film was pressed up to polished flange of round opening in the glass cell wall; a Teflon ring served as gasket. The working electrode active surface area was ~0.3 cm². All values of current, differential capacitance, and impedance components are given per 1 cm² of geometrical surface.

The impedance spectra were taken using a SOLARTRON SI 1280B spectra analyzer (Great Britain) in two modes: “f-sweep” (over 1 Hz to 20 kHz frequency range) and “E-sweep”. At special cases, the impedance was measured using an R-5021 ac bridge (Kiev, Ukraine) over 20 Hz to 200 kHz frequency range.

Potentiodynamic curves were taken using the SOLARTRON SI 1280B instrument. We used 0.5 M K₂SO₄ solution as indifferent electrolyte.

The working solution was 0.5 M K₂SO₄ saturated with benzene (reagent grade, mass fraction 99.8%). The benzene solubility in water is 0.07% (~2·10⁻² M) at 22°C [7].

3. Results and Discussion

3.1. Potentiodynamic Curves. In Figure 1, we give cyclic voltammograms taken in benzene-free 0.5 M K₂SO₄ solution (curves 1) and in the benzene-containing solution (curves 2). The curves 1 measured in the pure indifferent electrolyte solution relate to the oxygen anodic evolution. The high overvoltage of the process should be emphasized; it is typical for diamond electrodes. On the curve 2 (direct run) taken in the presence of benzene, we see current maximum, followed by a minimum, then the second current rise occurred, which is due to the concurrent benzene oxidation and oxygen...
3.2. The Impedance Spectra. The complex-plane plots of impedance spectra (that is, the –ImZ versus ReZ dependences) were measured at constant potential $E$ over the frequency $f$ range from 0.1 Hz to 15 kHz (in what follows, we refer to them as $f$-sweep plots). The $f$-sweep plots were taken in benzene-free 0.5 M $K_2SO_4$ solution (Figure 3) and in the benzene-containing solution (Figure 4). In Figure 4, the potential range covered the ideal polarizability region (from 0.4 to 1.2 V) and the anodic current rise (from 1.2 to 1.9 V), Figure 4(a), the region of the current decay (1.9 to 2.0 V), Figure 4(b), and the region of the second rise of the current (from 2.0 to 2.40 V), Figure 4(c) (in Figure 3, we divided the entire potential region into the like segments.)

We now analyze the shape of the $f$-sweep complex-plane plots in more detail. At less positive potentials (curves 1, 2 in Figures 3 and 4), we have straight lines somewhat declined to vertical line, which is characteristic of equivalent circuits including a constant phase element (CPE). With the increasing of positive potential, the charge-transfer resistance decreased, and the plots became curved, eventually turning into somewhat depressed semicircles. The difference of the low-frequency and high-frequency cutoffs of the “semicircles” equals the charge-transfer “faradaic” resistance $R_F$. It should be emphasized that in the background electrolyte solution (Figure 3), the changing of $R_F$ is monotonic, whereas in the benzene-containing solution (Figure 4), the value of $R_F$ first decreased (see Figure 4(a), curves 1–8), then
increased (Figure 4(b), curves 9–11), and finally decreased again (Figure 4(c), curves 12–19). It is easy to see that the character of changes in the value of $R_F$ closely correlates with the shape of the potentiodynamic curve 2 in Figure 1.

The high-frequency "halves" of the $f$-sweep complex-plane plots of impedance spectra (from the high-frequency cutoff up to the maximum) resemble more or less perfect semicircles, whereas the low-frequency halves are distorted by some slow processes whose nature is unknown. (Some considerations thereon are given in our earlier work [6]).

The high-frequency "halves" of the impedance spectra plots were interpreted by using a modified Ershler-Randles equivalent circuit called ZARC [9] (Figure 5(a)), in which a constant phase element (CPE) is substituted for the differential capacitance $C$. The ZARC circuit is widely used in the electrochemical impedance spectroscopy practice. Here the CPE impedance is $Z_{CPE} = \sigma^{-1}(i\omega)^{-a}$, where $\sigma$ is the frequency-independent factor; the exponent $a$ determines the character of frequency dependence; $\omega = 2\pi f$ is the ac angular frequency; $i = \sqrt{-1}$ is the imaginary unity.

The elements of the circuit, namely, the CPE parameters (the frequency-independent factor $\sigma$ and the exponent $a$), the charge-transfer resistance $R_F$ and series resistance $R_s$ were calculated from the impedance spectra (Figures 3 and 4)
by a standard fitting procedure; the standard deviation of calculated values from those experimentally measured did not exceed $10^{-3}$. (The experimentally measured impedance spectra were originally processed by using two equivalent circuits: the Ershler-Randles circuit (containing the capacitance $C$, see Figure 5(b)) and the ZARC circuit (containing the CPE, Figure 5(a)). When using Figure 5(a) circuit, the fitting relative error appeared being much less; therefore, we accepted this very circuit in our impedance calculations. We note that the numerical values of the differential capacitance $C$ (in $\mu$F/cm$^2$) and the factor $\sigma$ (in its accepted units) are quantities of the same order of magnitude, e.g., at $E = 0.7$ V, we have $C = 5.7, \sigma = 11$. In what follows, we shall often refer to both $C$ and $\sigma$ as “capacitance”, without loss of generality).

The Bode plot (the frequency dependence of the impedance modulus $|M|$, Figure 4(d)) is consistent with the results of the above analysis. At the potential of 1.4 V (in the ideal polarizability region), the straight line reflects but the CPE in the equivalent circuit. When the oxidation current flows, the charge-transfer resistance $R_F$ decreases (the more so, when the potential $E$ increased from 1.75 to 2.7 V) and thus contributes less to the $|M|$ value, the log $|M|$ versus log $f$ dependence saturates in the low-frequency region. In the high-frequency limit, we still have not reached saturation at $\approx 10,000$ Hz with our instrument; yet, we see faint resemblance of the saturation at a value of $\leq 10$ Ohm cm$^2$, which is close to the high-frequency cutoff in the complex-plane plots (Figures 3(a) and 4(a)). It is the solution resistance $R_s$ (see Figure 5) that contributes to $|M|$, along with the charge-transfer resistance $R_F$ and manifests itself at the higher frequencies.

In Figure 6, we show the potential dependence of $\sigma$ and $a$ (inset). In the ideal polarizability region (at potentials $E$ more negative than 1.2 V), the differential capacitance (more
precisely, the factor $\sigma$ depends but little on $E$; it is nearly the same both in the absence and in presence of benzene (compare curves 1 and 2 in Figure 6). Therefore, we conclude that in this potential region benzene does not adsorb on the diamond electrode (or its adsorption does not affect the electrode capacitance).

At potentials 1.5–1.6 V, the capacitance reaches its peak value. In the same potential region, the current-potential dependence in the indifferent electrolyte solution also reaches its peak value (a few $\mu$A/cm²), see Figure 7. According to [10], this current maximum is caused by the anodic oxidation of nondiamond ($sp^2$)-carbon composing intercrystalline boundaries; this material is less resistant toward oxidation than the crystalline ($sp^3$)-diamond. It seems not unwise to relate the capacitance (or pseudocapacitance?) maximum to the $sp^2$-carbon oxidation current.

At still more positive potentials where benzene is subject to active oxidation, the capacitance in the presence of benzene is considerably lower than in benzene-free solution. This can be explained by the adsorption of some intermediate of the benzene oxidation on the electrode, which results in the formation of dielectric interlayer [11]. In all probability, it is the same intermediate that blocks the anodic current (see Figures 1 and 2). At the potential of 2.2 V, the adsorbed product desorbs from the electrode or is subjected to further anodic oxidation, and the capacitance increased again.

The exponent $a$ somewhat differs from 1; it equals 0.8 to 0.9 (inset to Figure 6). Its weakly pronounced potential dependence may evidence some distribution of the reactants’ charge-transfer and mass-transfer activation parameters over the electrode surface [12]. Alternatively, it may be caused by concurrent adsorption of several benzene-oxidation intermediates with different activation energies.

The potential dependence of the differential faradaic conductivity of the electrode/electrolyte interface $Y = 1/R_F$ (Figure 8) resembles qualitatively the potential dependence of anodic current. In the region of the current blocking, the conductivity drops down, due to the adsorption of an intermediate. Then $Y$ increased again, thus reflecting the benzene oxidation and the parallel process of oxygen evolution (owing to water anodic oxidation).

3.3. The “E-Sweep Complex-Plane Plots” of Impedance Spectra. In addition to the complex-plane plots of impedance spectra obtained at constant potential and varying ac frequency (see the preceding Section), we measured complex-plane plots (the $-\text{Im} Z$ versus $\text{Re} Z$ dependences) of impedance at constant frequency, varying the potential $E$ (the so-called $E$-sweep, Figure 9). They were taken both in the indifferent electrolyte (curves 1) and in the presence of benzene (curves 2).

By inspecting the spectra in Figure 9, we see that, to the first approximation, they comprise two parts, namely, nearly vertical lines in the ideal polarizability region (which are even better pronounced at higher frequencies, see Figure 11(b) below), and “vertically arranged semicircles” that can be related to the charge transfer process at the interface during the oxidation process. It is these second parts that give information on the electrode reaction [13].

The equation describing these “polarization complex-plane plots” of impedance spectra can be easily derived for the simplest model. When the charge-transfer impedance includes contributions from the differential capacitance $C$ and faradaic conductivity $Y_F$ (connected in parallel in equivalent circuit) to the charge transfer flux

$$Z_k = \frac{1}{i\omega C + Y_F},$$

the equation for the complex-plane plot of the impedance is

$$\text{Re}^2 Z_k + \left(\text{Im} Z_k + \frac{1}{2i\omega C}\right)^2 = \left(\frac{1}{2i\omega C}\right)^2.$$  \hspace{1cm} (2)

With varying $Y_F$, we obtain a semicircle whose radius is inversely proportional to the electrical double layer capacitance $C$ and the angular frequency $\omega$. The distance of the

![Figure 9: Complex-plane plots of impedance spectra (E-sweep): (1) benzene-free solution and (2) benzene-containing solution. Arrows show the direction of potential sweep; the relevant potential values are shown at the curves.](image1)

![Figure 10: Complex-plane plots of impedance spectra (E-sweep, only direct runs), demonstrating the frequency effect on the small arc position: (1) 300 Hz, (2) 500 Hz, (3) 1000 Hz.](image2)
Figure 11: Complex-plane plots of impedance spectra (E-sweep) in 1 M KCl solution, demonstrating the frequency effect on the small arc position. (a) 60 Hz: (1) benzene-free solution and (2) benzene-containing solution. (b) 1000 Hz, benzene-containing solution. Arrows show the direction of potential sweep (0.4–2.5 V).

We note that after strong anodic polarization and subsequent return of potential to its initial (cathodic) value (see arrows in Figure 9, curves 1) the curve depicts a semicircle of larger radius (compare the curves obtained in the direct and the reverse run). At a fixed frequency, this can only be caused by decrease in the differential capacitance. The plausible reason of the decrease in the capacitance, hence, occurrence of the hysteresis may be irreversible adsorption of oxygen (formed during the water decomposition) and (in the presence of benzene) coadsorption of the benzene-oxidation intermediates.

When benzene is present in the solution (Figure 9, curves 2), the \(-\text{Im} Z \text{ versus Re} Z\) plots of direct run, measured at relatively low frequencies (30–100 Hz), show a short segment shaped as small arc. It is observed right in the potential region where the voltammogram (Figure 1, curve 2) showed a current peak and subsequent current decay. The small arc separates the semicircle's segments of different radii. At the reverse run of the curves the small arc used to be absent, probably, due to the electrode surface blocking by the oxidation intermediates. Importantly, at the reverse run of the cyclic voltammograms in the benzene-containing solution (Figure 1, curve 2), the benzene oxidation current is also absent right in the potential region when the direct voltammogram shows the current peak. Evidently, it is due to the surface blocking by the benzene-oxidation intermediate products. Thus, the small arc in the \(-\text{Im} Z \text{ versus Re} Z\) curves is a reflection of the anodic current maximum in the voltammogram. In the absence of faradaic current, the small arc in the reverse run of impedance complex-plane plots is also absent.

From the methodical point of view, it is of interest to reveal the effect of the ac measuring frequency on the position of the small arc in the impedance curve relative to the “central” (characteristic) point with the maximal ReZ. In the latter point, the capacitive and charge-transfer currents (hence, \(|\text{Im} Z|\) and \(\text{Re} Z\)) are equal to each other. The position of the small arc relative to this characteristic point in the \(-\text{Im} Z \text{ versus Re} Z\) plots is determined by the
3.4. Measurements in Phenol Solution. Above we showed that in the potential region of benzene oxidation the BDD-electrode surface is blocked by some intermediate products of the oxidative process. Among them, the former one in the reaction path is phenol that appears through a two-electron oxidation reaction (see, e.g., [8]). To reveal its possible effect on the impedance and charge transfer in the benzene system under study, we measured the potential dependences of anodic current (Figure 12) and differential capacitance (more precisely, the factor \( \sigma \), Figure 13) in 0.5 M \( \text{K}_2\text{SO}_4 \) solution in the absence and in the presence of phenol.

The cyclic voltammogram (Figure 12) by and large is similar to that given in [8]. The potential dependences of the capacitance in the ideal polarizability region both in the benzene- and phenol-containing solutions are basically similar (compare Figures 6 and 13). This allowed us to conclude that phenol, like benzene, does not adsorb on the diamond electrode. Hence, it is an intermediate other than phenol (that is, in higher oxidation state) that blocks the benzene oxidation current at the BDD electrode.

Interestingly, unlike Figure 6, no capacitance maximum is observed in the phenol solution at the potential of 1.5–1.6 V (Figure 13) where phenol is oxidized (whereas benzene is still stable against oxidation). Obviously, the phenol-oxidation intermediate adsors at the BDD and affects its surface properties in this potential region, in particular, lowering the capacitance.

4. Conclusions

Benzene oxidation at boron-doped diamond electrodes in 0.5 M \( \text{K}_2\text{SO}_4 \) aqueous solution is studied by cyclic voltammetry and electrochemical impedance spectroscopy. It is shown that in the ideal polarizability potential region benzene either does not adsorb at the diamond electrode or its adsorption does not affect the electrode capacitance. At more positive potentials, the “E-sweep” impedance measurements showed that the adsorption of some intermediate of benzene oxidation occurs at the electrode. The intermediate partially blocks the electrode surface and lowers the anodic current of benzene oxidation, however, without any effect on the oxygen evolution process. It is concluded that the electrode surface blocking is caused by an intermediate other than phenol.

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References
